

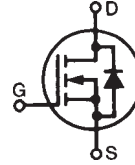
# HiPerFET™

## Power MOSFETs

### Q-Class

**IXFN 44N50Q**  
**IXFN 48N50Q**

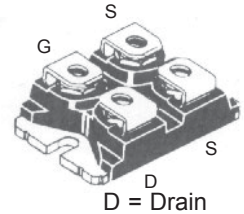
N-Channel Enhancement Mode  
Avalanche Rated, Low  $Q_g$ , High  $dv/dt$



| $V_{DSS}$ | $I_{D25}$ | $R_{DS(on)}$ |
|-----------|-----------|--------------|
| 500 V     | 44 A      | 120 mΩ       |
| 500 V     | 48 A      | 100 mΩ       |

$t_{rr} \leq 250$  ns

miniBLOC, SOT-227 B (IXFN)  
E153432



G = Gate  
S = Source

Either Source terminal at miniBLOC can be used as Main or Kelvin Source

#### Features

- IXYS advanced low  $Q_g$  process
- Low gate charge and capacitances
  - easier to drive
  - faster switching
- Unclamped Inductive Switching (UIS) rated
- Low  $R_{DS(on)}$
- Fast intrinsic diode
- International standard package
- miniBLOC with Aluminium nitride isolation for low thermal resistance
- Low terminal inductance (<10 nH) and stray capacitance to heatsink (<35pf)
- Molding epoxies meet UL 94 V-0 flammability classification

#### Applications

- DC-DC converters
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- Temperature and lighting controls

#### Advantages

- Easy to mount
- Space savings
- High power density

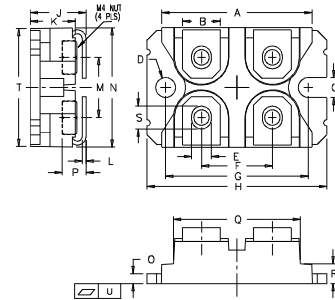
| Symbol               | Test Conditions                                                                                                  | Maximum Ratings  |                        |
|----------------------|------------------------------------------------------------------------------------------------------------------|------------------|------------------------|
| $V_{DSS}$            | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$                                                                  | 500              | V                      |
| $V_{DGR}$            | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GS} = 1$ MΩ                                                | 500              | V                      |
| $V_{GS}$             | Continuous                                                                                                       | ±20              | V                      |
| $V_{GSM}$            | Transient                                                                                                        | ±30              | V                      |
| $I_{D25}$            | $T_C = 25^\circ\text{C}$                                                                                         | 44N50<br>48N50   | 44<br>48 A             |
| $I_{DM}$             | $T_C = 25^\circ\text{C}$ , pulse width limited by $T_{JM}$                                                       | 44N50<br>48N50   | 176<br>192 A           |
| $I_{AR}$             | $T_C = 25^\circ\text{C}$                                                                                         | 48               | A                      |
| $E_{AR}$<br>$E_{AS}$ | $T_C = 25^\circ\text{C}$                                                                                         | 60<br>2.5        | mJ<br>mJ               |
| $dv/dt$              | $I_S \leq I_{DM}$ , $di/dt \leq 100$ A/μs, $V_{DD} \leq V_{DSS}$ ,<br>$T_J \leq 150^\circ\text{C}$ , $R_G = 2$ Ω | 15               | V/ns                   |
| $P_D$                | $T_C = 25^\circ\text{C}$                                                                                         | 500              | W                      |
| $T_J$                |                                                                                                                  | -55 to +150      | °C                     |
| $T_{JM}$             |                                                                                                                  | 150              | °C                     |
| $T_{stg}$            |                                                                                                                  | -55 to +150      | °C                     |
| $V_{ISOL}$           | 50/60 Hz, RMS $t = 1$ min<br>$I_{ISOL} \leq 1$ mA $t = 1$ s                                                      | 2500<br>3000     | V~<br>V~               |
| $M_d$                | Mounting torque<br>Terminal connection torque                                                                    | 1.5/13<br>1.5/13 | Nm/lb.in.<br>Nm/lb.in. |
| Weight               |                                                                                                                  | 30               | g                      |

| Symbol                                               | Test Conditions                                  | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                   |
|------------------------------------------------------|--------------------------------------------------|-----------------------------------------------------------------------------------|------|-------------------|
|                                                      |                                                  | min.                                                                              | typ. | max.              |
| $V_{DSS}$                                            | $V_{GS} = 0$ V, $I_D = 1$ mA                     | 500                                                                               |      | V                 |
| $V_{GS(th)}$                                         | $V_{DS} = V_{GS}$ , $I_D = 4$ mA                 | 2.0                                                                               |      | 4.0 V             |
| $I_{GSS}$                                            | $V_{GS} = \pm 20$ V <sub>DC</sub> , $V_{DS} = 0$ |                                                                                   |      | ±100 nA           |
| $I_{DSS}$                                            | $V_{DS} = V_{DSS}$<br>$V_{GS} = 0$ V             | $T_J = 25^\circ\text{C}$<br>$T_J = 125^\circ\text{C}$                             |      | 100<br>2 μA<br>mA |
| $R_{DS(on)}$                                         | $V_{GS} = 10$ V, $I_D = 0.5 I_{D25}$             | 44N50<br>48N50                                                                    |      | 120<br>100 Ω      |
| Pulse test, $t \leq 300$ μs, duty cycle $d \leq 2$ % |                                                  |                                                                                   |      |                   |

| Symbol       | Test Conditions                                                                                                | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |      |
|--------------|----------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|------|------|
|              |                                                                                                                | min.                                                                              | typ. | max. |
| $g_{fs}$     | $V_{DS} = 20\text{ V}; I_D = 0.5 \cdot I_{D25}$ , pulse test                                                   | 30                                                                                | 42   | S    |
| $C_{iss}$    | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$                                                  |                                                                                   | 7000 | pF   |
| $C_{oss}$    |                                                                                                                |                                                                                   | 960  | pF   |
| $C_{rss}$    |                                                                                                                |                                                                                   | 230  | pF   |
| $t_{d(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$<br>$R_G = 4.7\ \Omega$ (External), |                                                                                   | 33   | ns   |
| $t_r$        |                                                                                                                |                                                                                   | 22   | ns   |
| $t_{d(off)}$ |                                                                                                                |                                                                                   | 75   | ns   |
| $t_f$        |                                                                                                                |                                                                                   | 10   | ns   |
| $Q_{g(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$                                    |                                                                                   | 190  | nC   |
| $Q_{gs}$     |                                                                                                                |                                                                                   | 40   | nC   |
| $Q_{gd}$     |                                                                                                                |                                                                                   | 86   | nC   |
| $R_{thJC}$   |                                                                                                                |                                                                                   | 0.26 | K/W  |
| $R_{thCK}$   |                                                                                                                |                                                                                   | 0.05 | K/W  |

**Source-Drain Diode**

| Symbol   | Test Conditions                                                                                       | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |               |
|----------|-------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|------|---------------|
|          |                                                                                                       | min.                                                                              | typ. | max.          |
| $I_S$    | $V_{GS} = 0\text{ V}$                                                                                 |                                                                                   |      | 48 A          |
| $I_{SM}$ | Repetitive; pulse width limited by $T_{JM}$                                                           |                                                                                   |      | 192 A         |
| $V_{SD}$ | $I_F = I_S, V_{GS} = 0\text{ V}$ ,<br>Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $d \leq 2\%$ |                                                                                   |      | 1.5 V         |
| $t_{rr}$ | $I_F = 25\text{ A}, -di/dt = 100\text{ A}/\mu\text{s}, V_R = 100\text{ V}$                            |                                                                                   | 1.0  | 250 ns        |
| $Q_{RM}$ |                                                                                                       |                                                                                   |      | $\mu\text{C}$ |
| $I_{RM}$ |                                                                                                       |                                                                                   | 10   | A             |

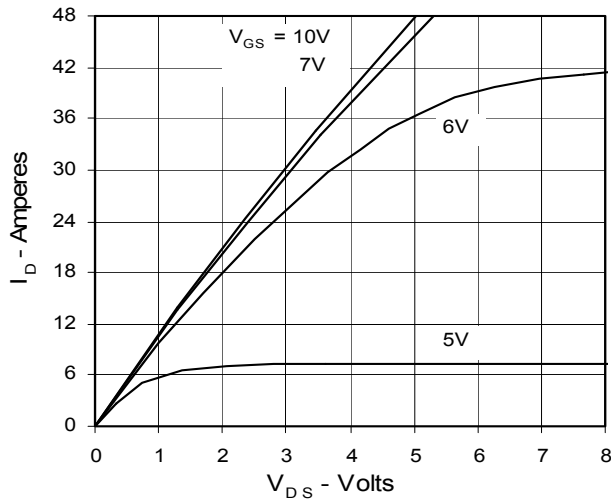
**miniBLOC, SOT-227 B**


M4 screws (4x) supplied

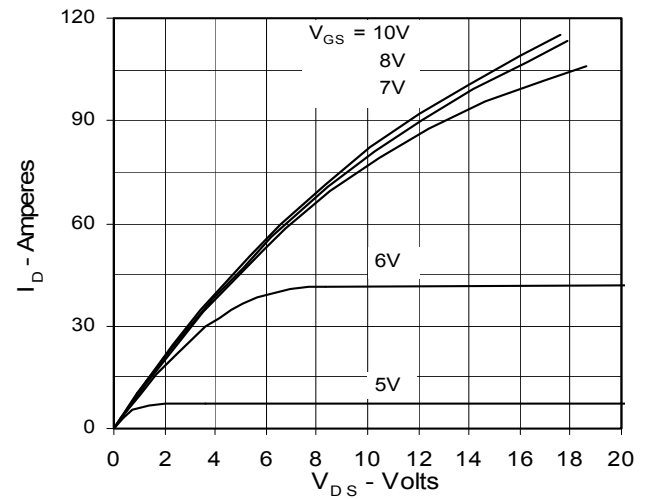
| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | Min.       | Max.  | Min.   | Max.  |
| A    | 31.50      | 31.88 | 1.240  | 1.255 |
| B    | 7.80       | 8.20  | 0.307  | 0.323 |
| C    | 4.09       | 4.29  | 0.161  | 0.169 |
| D    | 4.09       | 4.29  | 0.161  | 0.169 |
| E    | 4.09       | 4.29  | 0.161  | 0.169 |
| F    | 14.91      | 15.11 | 0.587  | 0.595 |
| G    | 30.12      | 30.30 | 1.186  | 1.193 |
| H    | 38.00      | 38.23 | 1.496  | 1.505 |
| J    | 11.68      | 12.22 | 0.460  | 0.481 |
| K    | 8.92       | 9.60  | 0.351  | 0.378 |
| L    | 0.76       | 0.84  | 0.030  | 0.033 |
| M    | 12.60      | 12.85 | 0.496  | 0.506 |
| N    | 25.15      | 25.42 | 0.990  | 1.001 |
| O    | 1.98       | 2.13  | 0.078  | 0.084 |
| P    | 4.95       | 5.97  | 0.195  | 0.235 |
| Q    | 26.54      | 26.90 | 1.045  | 1.059 |
| R    | 3.94       | 4.42  | 0.155  | 0.174 |
| S    | 4.72       | 4.85  | 0.186  | 0.191 |
| T    | 24.59      | 25.07 | 0.968  | 0.987 |
| U    | -0.05      | 0.1   | -0.002 | 0.004 |

IXYS reserves the right to change limits, test conditions, and dimensions.

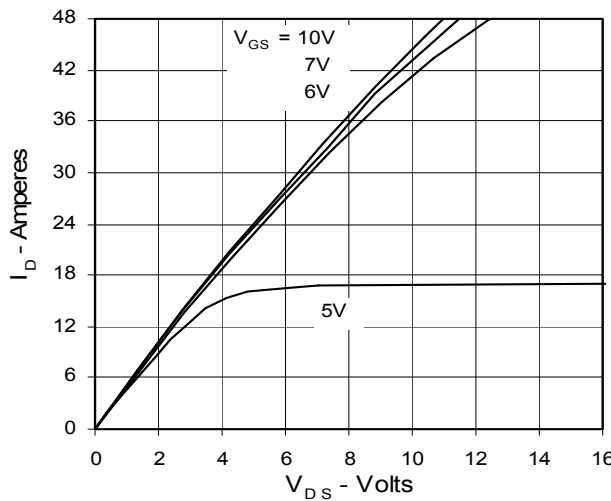
**Fig. 1. Output Characteristics  
@ 25 Deg. C**



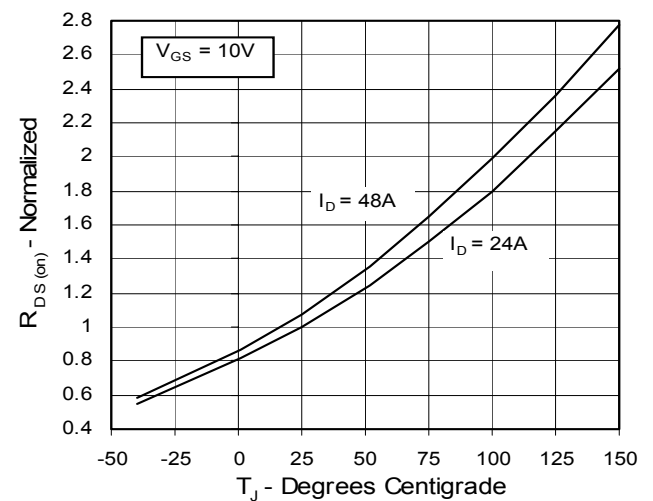
**Fig. 2. Extended Output Characteristics  
@ 25 deg. C**



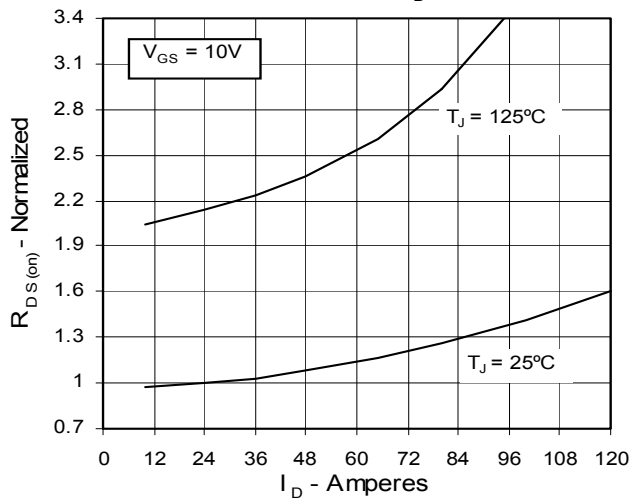
**Fig. 3. Output Characteristics  
@ 125 Deg. C**



**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_{D25}$  Value vs.  
Junction Temperature**



**Fig. 5.  $R_{DS(on)}$  Normalized to  $I_{D25}$   
Value vs.  $I_D$**



**Fig. 6. Drain Current vs. Case  
Temperature**

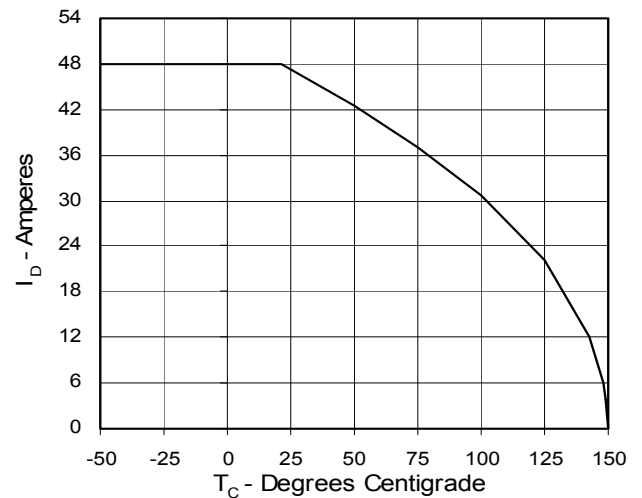


Fig. 7. Input Admittance

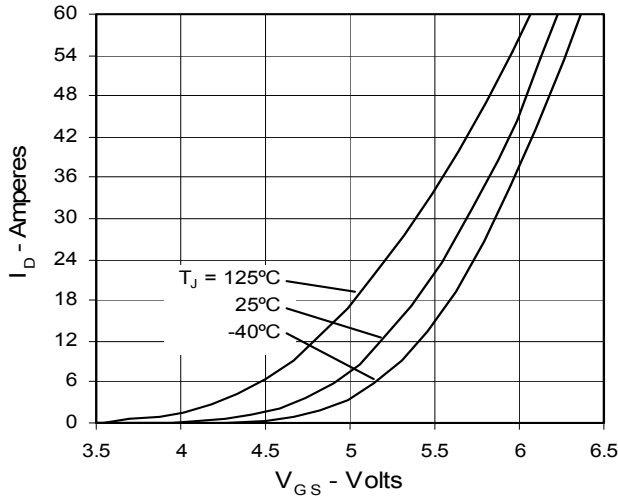


Fig. 8. Transconductance

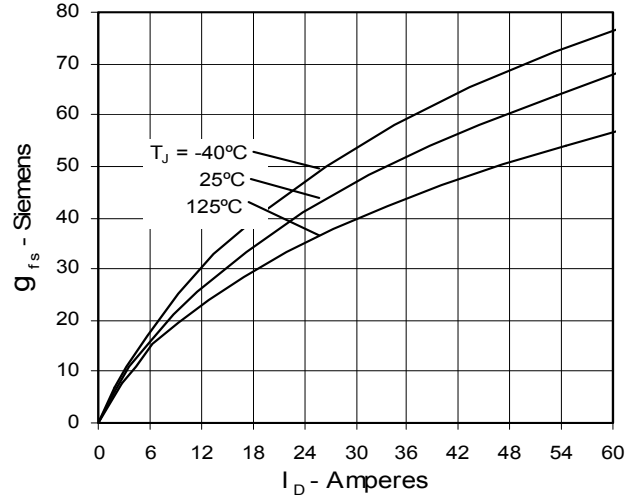


Fig. 9. Source Current vs. Source-To-Drain Voltage

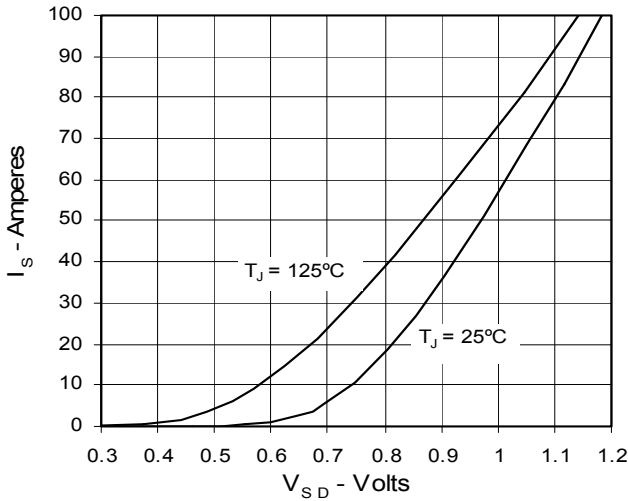


Fig. 10. Gate Charge

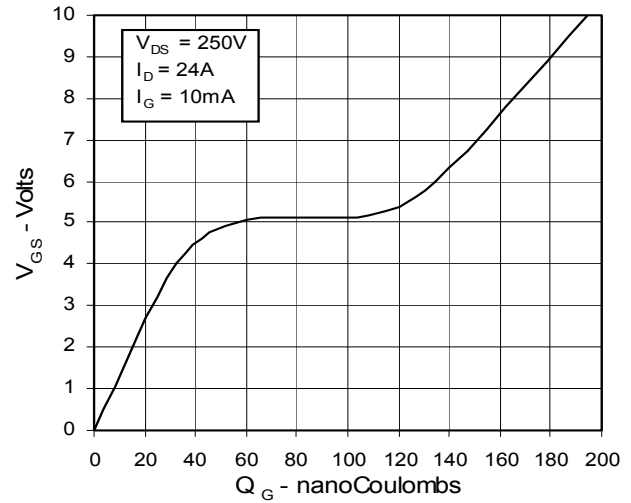


Fig. 11. Capacitance

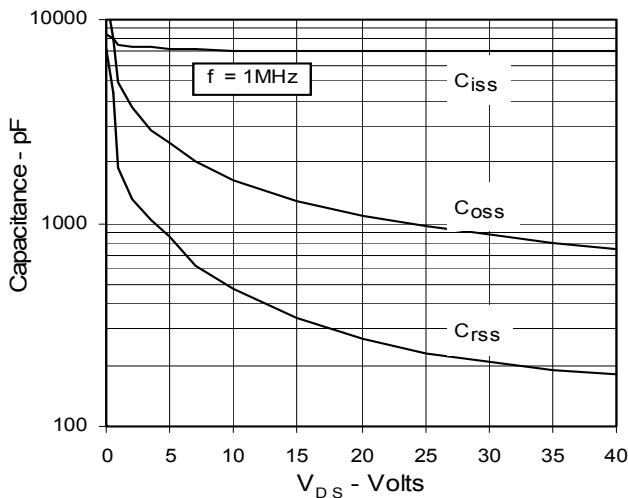
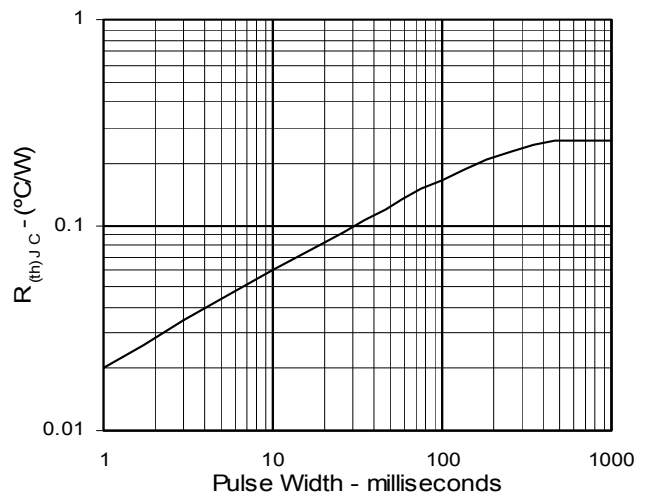


Fig. 12. Maximum Transient Thermal Resistance



IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

4,835,592 4,881,106 5,017,508 5,049,961 5,187,117 5,486,715 6,306,728B1 6,259,123B1 6,306,728B1  
4,850,072 4,931,844 5,034,796 5,063,307 5,237,481 5,381,025 6,404,065B1 6,162,665 6,534,343



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